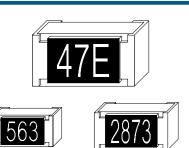
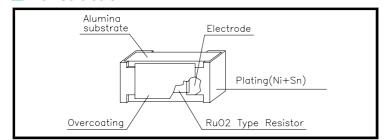
RTT 01,02,03,05,06,12,20,25

RALEC





Construction



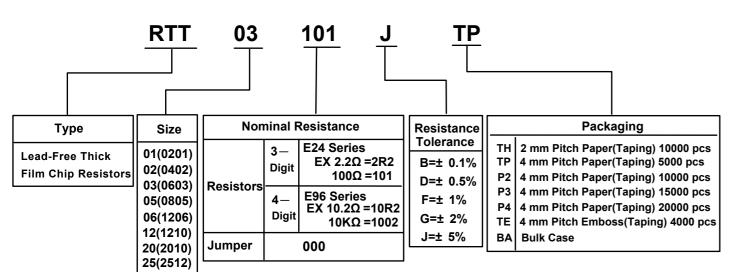
Feature

- 1.Small size and light weight.
- 2. High reliability and stability.
- 3.Lower assembly cost.
- 4. Apply to all kinds of SMT process.
- 5. Apply to Pb & Pb-Free Wave Solder & Reflow Solder.
- 6.Comply with RoHS.

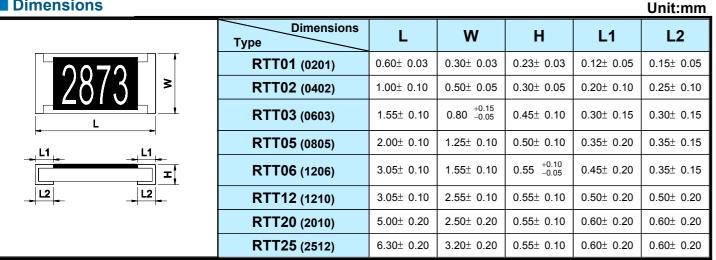
Application

- 1. Computer application, NB, MB, add-on card harddisk....
- 2. Mobile phone, Telecom....
- 3. Consumer electrial equipment, PDA, Digital Camera....
- 4. Battery changer, DC-DC power converter
- 5. Automotive

■ Type Designation



Dimensions



■ Standard Electrical Specifications

Thick Film Chip Resistors

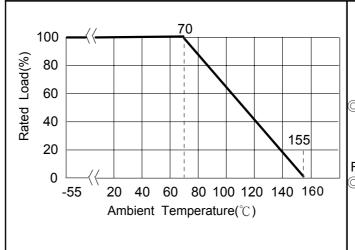
RTT 01,02,03,05,06,12,20,25

	Rated	Max.	Max.	T.C.R.	Resistance Range					Jumper	Jumper		
Type	Power at 70°C	Working Voltage	Overload Voltage	(ppm/℃)	B(± 0.1%) E-96	D(± 0.5%) E-96	F(± 1%) E-96	G(± 2%) E-24	J(± 5%) E-24	Rated Current	Resistance Value		
RTT01	1/20 W	25V	50V	± 600			1Ω~24.9Ω		1 Ω~ 24 . 9 Ω	0.5A	50m Ω		
(0201)	20 VV	250	30 V	± 250			25 Ω~10MΩ		25 Ω~10MΩ	0.5A	MAX		
RTT02	1/16 W	50V	100V	+500 -200		10Ω~99Ω	1Ω~9.9Ω	1Ω~9.9Ω	1Ω~9.9Ω	1A	50mΩ MAX		
(0402)				± 200	100 Ω~ 1M Ω	100 Ω~ 1M Ω	10 Ω~1MΩ	10 Ω~ 1M Ω	10 Ω ~ 20 M Ω		IVIAA		
RTT03	1			± 100	100 Ω~ 1M Ω	100 Ω~ 1M Ω	33 Ω~1MΩ				50m Ω		
(0603)	1/10 W	75V	150V	± 200		1Ω~99Ω	1Ω~32Ω 1.1M~10MΩ	1 Ω~ 10M Ω	1Ω~20MΩ	1A	MAX		
RTT05	1			± 100	100 Ω~ 1M Ω	100 Ω~ 1M Ω	33 Ω~1MΩ				50m Ω		
(0805)	<u>1</u> 8₩	150V	300V	± 200		1Ω~99Ω	1Ω~32Ω 1.1M~10M	1 Ω~ 10M Ω	1Ω~20MΩ	2A	MAX		
RTT06	1			± 100	100 Ω~ 1M Ω	100 Ω~ 1M Ω	33 Ω~1MΩ				50m Ω		
(1206)	1/4 W	200V	400V	± 200		1Ω~99Ω	1Ω~32Ω 1.1M~10MΩ	1 Ω~ 10M Ω	1Ω~20MΩ	2A	MAX		
				± 100	100 Ω ~ 1M Ω	100 Ω~ 1M Ω	33 Ω~1MΩ						
RTT12 (1210)	<u>1</u> 3₩	200V	400V	± 200			10Ω~32Ω 1.1M~10M	10Ω~10M	10 Ω~ 20M Ω	2A	50m Ω		
(-,				± 400			1Ω~9.9Ω	1Ω~9.9Ω	1Ω~9.9Ω				
RTT20	2			± 100			10 Ω~ 1M Ω				50mΩ		
(2010)	<u>3</u> ₩	200V	400V	± 200				10 Ω~ 1M Ω	10 Ω~ 10M Ω	2A	MAX		
(2010)				± 400			1Ω~9.9Ω	1Ω~9.9Ω	1Ω~9.9Ω		IVI/-VA		
RTT25				± 100			10 Ω~1MΩ				50m ()		
(2512)	1 1 1 1 1	200V	400V	± 200				10 Ω~ 1M Ω	10Ω~10MΩ	2A	50 m Ω		
(2312)				± 400			1Ω~9.9Ω	1 Ω ~9 . 9 Ω	1 Ω~ 9 . 9 Ω		WIZZX		
Operating Temperature Range					-55°C ~ +155°C (RTT01 : -55°C ~ +125°C)								

■ Taping Package

TVDE	Tape				Plastic Tape								
TYPE	Width		2mm	Pitch			4mm	Pitch		4mm Pitch			
		TH	H2	Н3	H4	TP	P2	P3	P4	TE	E2	E3	E4
0201	8 mm	10,000	20,000	30,000	40,000								
0402	8 mm	10,000	20,000	30,000	40,000								
0603	8 mm					5,000	10,000	15,000	20,000				
0805	8 mm					5,000	10,000	15,000	20,000				
1206	8 mm					5,000	10,000	15,000	20,000				
1210	8 mm					5,000	10,000	15,000	20,000				
2010	12 mm									4,000	8,000	12,000	16,000
2512	12 mm									4,000	8,000	12,000	16,000

■ Power Derating Curve



Marking



FOR E-24&E-96

○2%,5% 3 digits indication

first 2 digits are significant figures 3rd digit is multiplier(10[×])

EX. Marking --> 563

 $56 \times 10^3 = 56000 \Omega = 56 \text{K} \Omega$

0.1% \ 0.5% \ 1% 4 digits indication

first 3 digits are significant figures 4th digit is multiplier (10^x) EX. Marking --> 3922

 $392 \times 10^2 = 39200 \Omega = 39.2 \text{K}\Omega$

FOR RTT03 0.1% \ 0.5% \ 1%(E-96)

3 digit indication

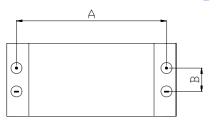
first 2 digits are significant for E-96 Part marking scheme. 3rd digit is multiplier:

Y=10⁻² $X = \dot{10}^{-1}$ $A=10^{0}$ $C=10^{2}$ $D=10^{3}$

B=101 E=104 F=10⁵

Type RTT01,02:No marking Code

■ Measurement Point For Chip Resistors

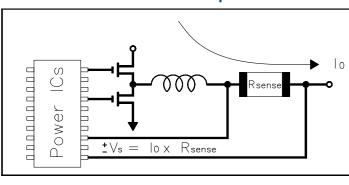


• Current Terminal

Voltage Terminal

DIM	A	В
RTT01	0.45± 0.05	0.22 ± 0.05
RTT02	0.80± 0.05	0.35 ± 0.05
RTT03	1.35± 0.05	0.35 ± 0.05
RTT05	1.80 ± 0.05	0.35 ± 0.05
RTT06	2.90 ± 0.05	0.35 ± 0.05
RTT12	2.90 ± 0.05	0.35 ± 0.05
RTT20	4.50 ± 0.05	1.15 ± 0.05
RTT25	5.90 ± 0.05	1.60 ± 0.05

■ Function For Low-Ohmic Chip Resistors



Selection of R sense:

On general case, the feedback voltage is set arount 100 mV.

100 mV = I_0 x R sense

where I_0 means the maximum average output current.

■ Standard Resistance Values

For 2%,5%(E-24)

10	11	12	13	15
16	18	20	22	24
27	30	33	36	39
43	47	51	56	62
68	75	82	91	

For	1%	(E-96
ıvı	1 / 0	1 L -JU

1 01	1 /0(= -	<i>,</i>									
100	102	105	107	110	113	115	118	121	124	127	130
133	137	140	143	147	150	154	158	162	165	169	174
178	182	187	191	196	200	205	210	215	221	226	232
237	243	249	255	261	267	274	280	287	294	301	309
316	324	332	340	348	357	365	374	383	392	402	412
422	432	442	453	464	475	487	499	511	523	536	549
562	576	590	604	619	634	649	665	681	698	715	732
750	768	787	806	825	845	866	887	909	931	953	976

■ Alternate Marking Method

For RTT03 1%(E-96)

		• /0(=	••,												
Code	R Value	Code	R Value	Code	R Value	Code	R Value	Code	R Value	Code	R Value	Code	R Value	Code	R Value
1	100	13	133	25	178	37	237	49	316	61	422	73	562	85	750
2	102	14	137	26	182	38	243	50	324	62	432	74	576	86	768
3	105	15	140	27	187	39	249	51	332	63	442	75	590	87	787
4	107	16	143	28	191	40	255	52	340	64	453	76	604	88	806
5	110	17	147	29	196	41	261	53	348	65	464	77	619	89	825
6	113	18	150	30	200	42	267	54	357	66	475	78	634	90	845
7	115	19	154	31	205	43	274	55	365	67	487	79	649	91	866
8	118	20	158	32	210	44	280	56	374	68	499	80	665	92	887
9	121	21	162	33	215	45	287	57	383	69	511	81	681	93	909
10	124	22	165	34	221	46	294	58	392	70	523	82	698	94	931
11	127	23	169	35	226	47	301	59	402	71	536	83	715	95	953
12	130	24	174	36	232	48	309	60	412	72	549	84	732	96	976
Y=10 ⁻²	² X='	$X=10^{-1}$ A=10 ⁰ B=10 ¹ C=10 ² D=10 ³ E=10 ⁴ F=10				=10⁵		·							

3

Thick Film Chip Resistors RTT 01,02,03,05,06,12,20,25

■ Reliability Test

		Specification	on				
ltem	R:≧	1 Ω	R :<1Ω	Test Method			
	0.5% \ 1%	2% \ 5%	1% \ 2% \ 5%				
Temperature Coefficient of Resistance	Wit	thin the specification	n of TCR	JIS-C5202-5.2 TCR (ppm/°C) = $\frac{(R2-R1)}{R1 (T2-T1)} \times 10$ R1: Resistance at room temperature R2: Resistance at -55°C or +125°C T1: Room temperature T2:Temperature -55°C or +125°C (RTT01 at 125°C)			
Short Time Overload	± (1.0%+0.05Ω)	± (2.0%+0.10Ω)	± (2.0%+0.001Ω)	JIS-C5202-5.5 Apply 2.5 times rated voltage or Max. Overload Voltage for 5 seconds.			
Insulation Resistance		$≥10^{9}Ω$		JIS-C5202-5.6 Put the resistor in the fixture, add 100 VDC in +,-terminal for 60 seconds then measured the insulation resistance.			
Dielectric Withstand Voltage	No sh	ort or burned on the	appearance	JIS-C5202-5.7 Apply 500VAC for 1min.(RTT02,0 300VAC).			
Intermittent Overload	± (5.0%-	+0.10Ω)	± (5.0%+0.001Ω)	JIS-C5202-5.8 Apply rated voltage 2.5 times, 1sec ON, 25sec OFF, 10000 test cycle.			
Core Body Strength	± (1.0%-	+0.05Ω)	± (1.0%+0.001Ω)	JIS-C5202-6.1.4 Applied R0.5 test probe at its central part then pushing 1Kgf force on the sample for 10 sec.			
Terminal Strength	No e	evidence of mechani	cal damage	JIS-C5202-6.1.4 Apply 5N pushing force for 10sec.			
Resistance to Solvent	± (0.5%+0.05Ω)		± (1.0%+0.001Ω)	JIS-C5202-6.9 Immersed into ispropyl alcohol of 20 ~ 25°C for 60 seconds.			
Resistance to Soldering Heat	± (1.0%	+ 0.05 Ω)	± (1.0%+0.001Ω)	By SONY SS-00254-5, JIS-C5202-6.10			
Solderability		Coverage ≥ 95%	%	By SONY SS-00254-2, JIS-C5202-6.11			
Joint strength of solder	After application of		\pm (1.0%+0.001 Ω) adhesion or bending	By SONY SS-00254-7, JIS-C5202-6.1.4			
	load should be 50°	% or more of initial s		D., CONIV. CC. 00254.0			
Leaching Test		Coverage ≥ 95%	% I	By SONY SS-00254-9			
Vibration	± (0.5%+0.05Ω)	± (1.0%+0.05Ω)	± (1.0%+0.001Ω)	JIS-C5202-6.3 Frequency range:10 Hz to 55Hz to 10Hz/1min. Amplitude:1.5 mm This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (a total of 6 hrs).			
Resistance to Dry Heat	$\pm (1.0\% + 0.05\Omega)$	± (2.0%+0.10Ω)	± (1.0%+0.001Ω)	JIS-C5202-7.2 1000 Hrs at 155℃. (RTT01 at 125 ℃)			
Thermal Shock	ock $\pm (0.5\% + 0.05\Omega) \pm (1.0\% + 0.05\Omega) \pm (1.0\% + 0.001\Omega)$			MIL-STD 202 Method 107 Cycle between -55°C and +125°C 15 minute for 300 cycles.			
Loading Life in Moisture	$\pm (0.5\% + 0.05\Omega)$	± (2.0%+0.10Ω)	± (2.0%+0.001Ω)	JIS-C5202-7.9 40± 2°C,90~95 %RH ,1000Hrs at RCWV, 1.5Hrs ON, 0.5Hrs OFF.			
Load Life	$\pm (1.0\% + 0.05\Omega)$	± (3.0%+0.10Ω)	± (2.0%+0.001Ω)	JIS-C5202-7.10 70℃, 1000Hrs at RCWV, 1.5Hr ON, 0.5Hr OFF			
Low Temperature Operation	$\pm (0.5\% + 0.05\Omega)$	$\pm (1.0\% + 0.05\Omega)$	± (1.0%+0.001Ω)	MIL-R-5532D 4.7.4 1 Hrs, -55℃ ,Followed by 45 minutes of RCWV.			
Whisker Test		Max 50 μ m		By SONY SS-00254-8, JIS-C5202			

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RCWV=Rated Continuous Working Voltage